PATENT S/N 08/903486

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Leonard Forbes et al.

Examiner: Donghee Kang

Serial No.:

08/903486

Group Art Unit: 2811

Filed:

July 29, 1997

Docket: 303.326US1

SILICON CARBIDE GATE TRANSISTOR

COMMUNICATION CONCERNING RELATED APPLICATION

TRADEST missioner for Patents

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۵í	Gommissioner fo	or Patents		NOV 0 6 2003
	P.O. Box 1450 Alexandria, VA	22313-1450		Technology Center 2100
	Applican	ts would like to	bring to the Examine	er's attention the following related
	Serial/Patent No. 08/903452	Filing Date July 29, 1997	Attorney Docket 303.324US1	Title TRANSISTOR WITH VARIABLE ELECTRON AFFINITY GATE AND METHODS OF FABRICATION AND USE
	09/256643	February 23, 1999	303.324US2	TRANSISTOR WITH VARIABLE ELECTRON AFFINITY GATE AND METHODS OF FABRICATION AND USE
	09/652420	August 31, 2000	303.324US3	TRANSISTOR WITH VARIABLE ELECTRON AFFINITY GATE AND METHODS OF FABRICATION AND USE
	09/691004	October 18, 2000	303.324US4	TRANSISTOR WITH VARIABLE ELECTRON AFFINITY GATE AND METHODS OF FABRICATION AND USE
	09/259870	March 1, 1999	303.326US2	FABRICATION OF SILICON CARBIDE GATE TRANSISTOR
	08/902132 5886368	July 29, 1997	303.353US1	TRANSISTOR WITH SILICON OXYCARBIDE GATE AND METHODS OF FABRICATION AND USE
	09/138294	August 21,	303.353US2	TRANSISTOR WITH SILICON

COMMUNICATION CONCERNING CO-PENDING APPLICATIONS Serial Number: 08/903486 Filing Date: July 29, 1997 Title: SILICON CARBIDE GATE TRANSISTOR

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6309907	1998		OXYCARBIDE GATE AND METHODS OF FABRICATION AND USE
08/902843	July 29, 1997	303.354US1	DEAPROM HAVING AMORPHOUS SILICON CARBIDE GATE INSULATOR
09/135413	August 14, 1998	303.354US2	METHOD FOR OPERATING A DEAPROM HAVING AN AMORPHOUS SILICON CARBIDE GATE INSULATOR
09/134713	August 14, 1998	303.354US3	DEAPROM HAVING AMORPHOUS SILICON CARBIDE GATE INSULATOR
08/902098 6031263	July 29, 1997	303.355US1	DEAPROM AND TRANSISTOR WITH GALLIUM NITRIDE OR GALLIUM ALUMINUM NITRIDE GATE
09/140978 6307775	August 27, 1998	303.355US2	DEAPROM AND TRANSISTOR WITH GALLIUM NITRIDE OR GALLIUM ALUMINUM NITRIDE GATE
09/141392 6249020	August 27, 1998	303.355US3	DEAPROM AND TRANSISTOR WITH GALLIUM NITRIDE OR GALLIUM ALUMINUM NITRIDE GATE
09/883795	June 18, 2001	303.355US4	DEAPROM AND TRANSISTOR WITH GALLIUM NITRIDE OR GALLIUM ALUMINUM NITRIDE GATE
10/047181	October 23, 2001	303.355US5	DEAPROM AND TRANSISTOR WITH GALLIUM NITRIDE OR GALLIUM ALUMINUM NITRIDE GATE
08/902133	July 29, 1997	303.356US1	DYNAMIC ELECTRICALLY ALTERABLE PROGRAMMABLE READ ONLY MEMORY DEVICE

COMMUNICATION CONCERNING CO-PENDING APPLICATIONS

Serial Number: 08/903486 Filing Date: July 29, 1997

Title: SILICON CARBIDE GATE TRANSISTOR

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10/231687	August 29, 2002	303.356US2	DYNAMIC ELECTRICALLY ALTERABLE PROGRAMMABLE READ ONLY MEMORY DEVICE
08/903453	July 29, 1997	303.378US1	CARBURIZED SILICON GATE INSULATORS FOR INTEGRATED CIRCUITS
09/258467	February 26, 1999	303.378US2	CARBURIZED SILICON GATE INSULATORS FOR INTEGRATED CIRCUITS
09/650553	August 30, 2000	303.378US3	CARBURIZED SILICON GATE INSULATORS FOR INTEGRATED CIRCUITS
10/461593	June 11, 2003	303.356US3	DYNAMIC ELECTRICALLY ALTERABLE PROGRAMMABLE READ ONLY MEMORY DEVICE

Respectfully submitted,

LEONARD FORBES ET AL.

By Applicants' Representatives,

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CERTIFICATE UNDER 37 CFR 1.8: The undersigned hereby certifies that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail, in an envelope addressed to: Commissioner of Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on this 31st day of October, 2003.

Signature

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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SILICON CARBIDE GATE TRANSISTOR

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Commissioner for Patents

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Alexandria, VA 22313-1450



Serial No.: 08/903486

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We are transmitting herewith the following attached items (as indicated with an "X"):

- \underline{X} A return postcard.
- X An Amendment and Response (14 Pages).
- X An Supplemental Information Disclosure Statement (2 pgs.), Form 1449 (3 pgs.), and copies of 54 cited documents.
- \underline{X} A check in the amount of \$180.00 to cover the fee for consideration of Information Disclosure Statement under 97(c).
- X Communication Concerning Co-Pending Applications (3 pgs.).

Please consider this a PETITION FOR EXTENSION OF TIME for sufficient number of months to enter these papers and please charge any additional fees or credit overpayment to Deposit Account No. 19-0743.

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.

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Atty: Robert E. Mates Reg. No. 35,271

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